

NPN SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING

The 2SC4351 is a high-speed Darlington power transistor. This transistor is ideal for high-precision control such as PWM control for pulse motors or blushless motor of OA and FA equipment.

FEATURES

NEC

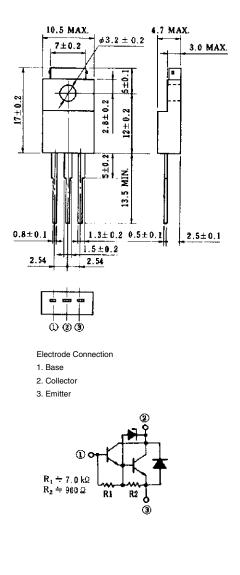
- Mold package that does not require an insulating board or insulation bushing
- On-chip C to B constant voltage diode for surge voltage absorption
- On-chip C to E reverse diode
- · Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	60 ± 10	V
Collector to emitter voltage	VCEO	60 ± 10	V
Emitter to base voltage	Vebo	8.0	V
Collector current (DC)	IC(DC)	±5.0	А
Collector current (pulse)	C(pulse)*	±10	А
Base current (DC)	B(DC)	0.5	А
Total power dissipation	P⊤ (Tc = 25°C)	20	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

* PW \leq 10 ms, duty cycle \leq 50%

PACKAGE DRAWING (UNIT: mm)



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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

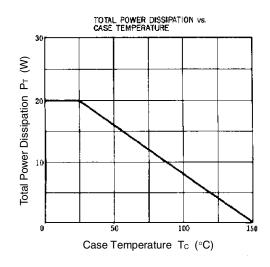
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 40 V, I_E = 0$			0.5	μA
DC current gain	hfe1*	Vce = 2.0 V, Ic = 2.0 A	2,000		20,000	
DC current gain	hfe2*	Vce = 2.0 V, Ic = 4.0 A	500			
Collector saturation voltage	V _{CE(sat)} *	Ic = 2.0 A, I _B = 2.0 mA			1.5	V
Base saturation voltage	V _{BE(sat)} *	Ic = 2.0 A, I _B = 2.0 mA			2.0	V
Turn-on time	ton	Ic = 2.0 A, I _{B1} = −I _{B2} = 2.0 mA, R _L = 25 Ω, V _{CC} \cong 50 V Refer to the test circuit.		0.7		μs
Storage time	tstg			2.5		μs
Fall time	tr			0.6		μs

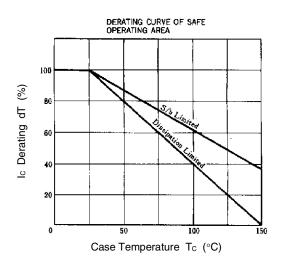
* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

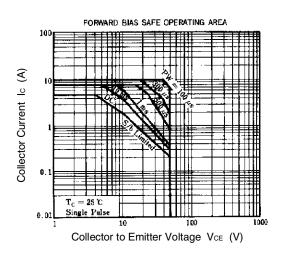
hfe CLASSIFICATION

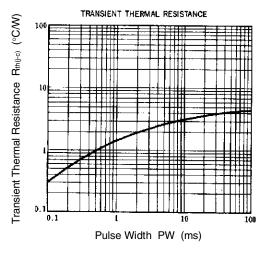
Marking	М	L	к
hfe1	2,000 to 5,000	4,000 to 10,000	8,000 to 20,000

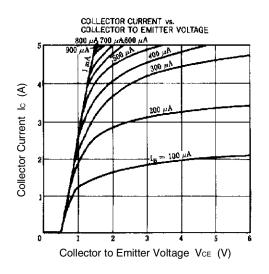
TYPICAL CHARACTERISTICS (Ta = 25°C)

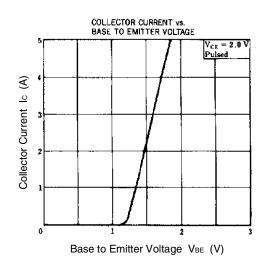


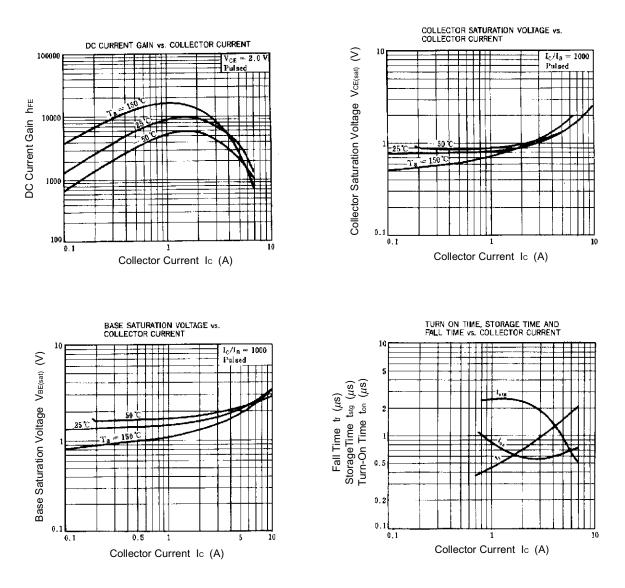




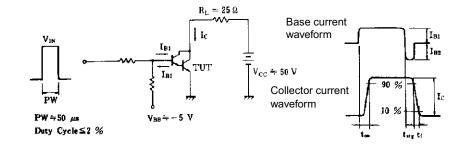








SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



Data Sheet D15594EJ2V0DS

[MEMO]

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